

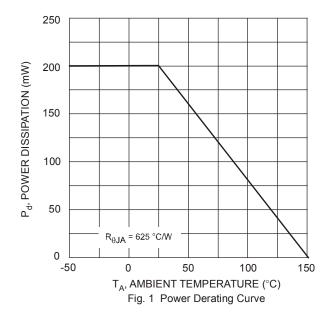
Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Supply Voltage <pin: (2)="" (3)="" to=""></pin:>		V _{CC}	50	V	
Input Voltage <pin: (1)="" (2)="" ddtd122lc<br="" to="">DDTD142JC</pin:>		V _{IN}	-5 to +6 -5 to +6	V	
Input Voltage <pin: (1)<="" (2)="" td="" to=""><td>DDTD122TC DDTD142TC</td><td>VEBO (MAX)</td><td>5</td><td>v</td></pin:>	DDTD122TC DDTD142TC	VEBO (MAX)	5	v	
Output Current	-	Ι _C	500	mA	

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	200	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	R _{0JA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Note: 5. Mounted on FR4 PC board with recommended pad layout.





Electrical Characteristics - R1, R2 Types (@ T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Мах	Unit	Test Condition
Input Voltage	DDTD122LC DDTD142JC	V _{l(off)}	0.3 0.3	_	_	V	V _{CC} = 5V, I _O = 100μA
	DDTD122LC DDTD142JC	V _{l(on)}	_	_	2.0 2.0	V	V _O = 0.3V, I _O = 20mA V _O = 0.3V, I _O = 20mA
Output Voltage		V _{O(on)}	_	_	0.3V	V	I _O /I _I = 50mA/2.5mA
Input Current	DDTD122LC DDTD142JC	I	_		28 13	mA	V _I = 5V
Output Current		I _{O(off)}			0.5	μA	$V_{CC} = 50V, V_1 = 0V$
DC Current Gain	DDTD122LC DDTD142JC	GI	56 56	_		_	V _O = 5V, I _O = 50mA
Gain-Bandwidth Product (Note 6)		f _T	_	200	_	MHz	V _{CE} = 10V, I _E = 5mA, f = 100MHz

Electrical Characteristics - R1- Only, R2- Only Types (@ T_A = +25°C, unless otherwise specified.)

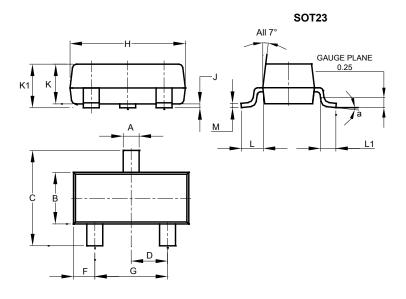
Characteristic		Symbol	Min	Тур	Мах	Unit	Test Condition
Characteristic		Cynhol		٩٤	max	Unit	
Collector-Base Breakdown Voltage		BV _{CBO}	50	_	—	V	I _C = 50μΑ
Collector-Emitter Breakdown Voltage		BV _{CEO}	40	_	_	V	I _C = 1mA
Emitter-Base Breakdown Voltage	DDTD122TC DDTD142TC	BV _{EBO}	5		_	V	I _E = 50μA I _E = 50μA
Collector Cut-Off Current		I _{CBO}	_		0.5	μA	V _{CB} = 50V
Emitter Cut-Off Current	DDTD122TC DDTD142TC	I _{EBO}			0.5 0.5	μA	V _{EB} = 4V
Collector-Emitter Saturation Voltage		V _{CE(sat)}	—	—	0.3	V	I _C = 50mA, I _B = 2.5mA
DC Current Transfer Ratio	DDTD122TC DDTD142TC	h _{FE}	100 100	250 250	600 600		I _C = 5mA, V _{CE} = 5V
Gain-Bandwidth Product (Note 6)		f⊤		200	_	MHz	V _{CE} = 10V, I _E = -5mA, f = 100MHz

Note: 6. Transistor – For Reference Only



Package Outline Dimensions

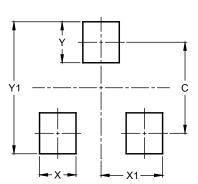
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT23						
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
Μ	0.085	0.150	0.110				
а	0°	8°					
All	All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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